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## **BIB DATA SHEET**

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APPLICANTS  Yasuo Kobayashi, Yamanashi-Ken, JAPAN; Kohei Kawamura, Yamanashi-Ken, JAPAN; Tadahiro Ohmi, Miyagi-Ken, JAPAN; Akinobu Teramoto, Miyagi-Ken, JAPAN; Tatsuya Sugimoto, Tokyo-To, JAPAN; Toshiro Yamada, Tokyo-To, JAPAN; Kimiaki Tanaka, Tokyo-To, JAPAN;					
** CONTINUING DATA ******************* This application is a 371 of PCT/JP04/11595 08/12/2004 /RP/					
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ADDRESS					
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